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PHOTOMULTIPLIER TUBE **R9182-01** (Cooled PMT)

28 mm (1-1/8 Inch) Diameter, Side-on Type Compatible Pin Layout with Any 28 mm dia. Side-on PMT Dark Current Becomes 1/50 by Cooling, For UV to NIR

(at DE OC)

CHARACTERISTICS

				(a	125 0
	Parameter	Min.	Тур.	Max.	Unit
Cathodo	Luminous (2856 K)	400	525	—	μA/Im
Sanaitivity	Quantum Efficiency at 450 nm	—	25	—	%
Sensitivity	Blue Sensitivity Index (CS 5-58)	_	13	_	
Anode Sensitivity	Luminous (2856 K)	3000	5000	—	A/lm
Gain		—	$9.5 imes10^{6}$	—	
Anode Dar	k Current	_	15	50	nA
(After 30 m	in Storage in Darkness)		0.3 ^(A)	1 ^(A)	nA
Time	Anode Pulse Rise Time		2.2		ns
Response	Electron Transit Time		22		ns



Left: R9182-01, Right: R928

NOTE: (A) The values are measured at 25 °C and a Peltier supply current of 2.7 A, with a heatsink attached to the R9182-01 for forced air cooling.

CHORE BRUITUR (MW)

Figure 1: Typical Spectral Response

Figure 2: Typical Gain Characteristics



Figure 3: Temperature vs. Dark Current Characteristics with and without Cooling



AMBIENT TEMPERATURE (°C)

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PHOTOMULTIPLIER TUBE R9182-01 (Cooled PMT)

SPECIFICATIONS

GENERAL

Parameter Description / Value						
Spectral Respo	onse	185 to 900	nm			
Wavelength of	Maximum Response	450	nm			
Photocathodo	Material	Multialkali	—			
FIIOlocaliioue	Minimum Effective Area	10 × 14	mm			
Window Mater	low Material UV glass					
Dynada	Structure	Circular-cage	_			
Dynoue	Number of Stages	9	_			
Base		11-pin base JEDEC No. B11-88				
Weight		Approx. 63	g			
Operating Amb	pient Temperature	-30 to +50	°C			
Storage Tempe	erature	-30 to +50	°C			
Suitable Socke	et	E678-11A (Sold separately)				
Suitable Socke	et Assembly	E717-63 (Sold separately)	_			

MAXIMUM RATINGS (Absolute Maximum Values)

	Parameter	Value	Unit
Supply	Between Anode and Cathode	1250	V
Voltage	Between Anode and Last Dynode	250	V
Average	e Anode Current	0.1	mΑ

VOLTAGE DISTRIBUTION RATIO AND SUPPLY VOLTAGE

Ratio 1 1 1 1 1 1 1 1 1 1 1	Electrodes	k	(Dy	/1	D	y2	Dy	/3	Dy	/4	Dy	/5	Dy	/6	Dy	y7	Dy	y8	Dy	9	F	>
	Ratio		1		1		1		1		1	1	1		1		-	1	1		1		

Supply Voltage: 1000 V, K: Cathode, Dy: Dynode, P: Anode

PELTIER DEVICE

Parameter	Description / Value	Unit
Maximum Cooling Capacity (Qmax.)	8.2	W
Maximum Supply Current	2.7	Α
Maximum Applied Voltage	3.0	V
Maximum Operating Temperature	50	°C
Leak Current Between		n۸
Cathode and Peltier GND		IIA

NOTE: (1)Insulation resistance at 25 °C: $1.0 \times 10^{14} \Omega$

PELTIER COOLING PERFORMANCE

Parameter	Description / Value	Unit
Cathode Cooling Temperature (ΔT)	20 ②	°C
Time Required to Reach	E ③	min
Target Cooling Temperature	5	111111

NOTE: ②, ③At a supply current of 2.7 A and with a heatsink attached to the R9182-01 for forced air cooling.

Cooling temperature (ΔT) is the difference between the ambient temperature and the cathode temperature when fully cooled.

When attaching a heatsink to the R9182-01, apply thermal grease to the surface of the Peltier device so that the heat on the hot side dissipates efficiently through the heatsink during operation.

Temperature should be controlled by current during operation of the Peltier device.

Figure 4: Dimensional Outline and Basing Diagram (Unit: mm)



RELATED PRODUCTS /



*Module: PMT, Voltage divider circuit and high voltage power supply incorporated in the package.

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